VS-VSKCS401/045

Vishay Semiconductors



AAP Gen 7 (TO-240AA) **Power Modules Schottky Rectifier, 400 A**



AAP Gen 7 (TO-240AA)

PRIMARY CHARACTERISTICS				
I _{F(AV)}	400 A			
V _R	45 V			
Package	AAP Gen 7 (TO-240AA)			
Circuit configuration	Two diodes common cathode			

MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996
- · Designed and gualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKCS401.. Schottky rectifier common cathode has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	400	А	
V _{RRM}		45	V	
I _{FSM}	t _p = 5 μs sine	29 000	А	
V _F	200 A _{pk} , T _J = 125 °C	0.69	V	
TJ	Range	-55 to +175	°C	

VOLTAGE RATINGS				
PARAMETER SYMBOL		VS-VSKCS401/045	UNITS	
Maximum DC reverse voltage	V _R	45	V	
Maximum working peak reverse voltage	V _{RWM}	45	v	

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ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	L TEST CONDITIONS V		VALUES	UNITS
Maximum average	per module		50.0% dute such at T 100.00 matter subscription		400	
forward current	per leg	IF(AV)	$I_{F(AV)}$ 50 % duty cycle at T _C = 120 °C, rectangular waveform	200		
Maximum peak one cycle non-repetitive surge current			5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	29 000	A
	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	3400		
Non-repetitive avalanche energ	у	E _{AS}	T _J = 25 °C, I _{AS} = 24 A, L = 1 mH		270	mJ
Repetitive avalanche current		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 40		А	

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	200 A	T _J = 25 °C	0.72	v
		400 A		0.98	
		200 A	T _J = 125 °C	0.69	
		400 A		0.96	
Maximum rayaraa laakaga aurrant	I _{RM}	$T_J = 25 \ ^{\circ}C$	V _R = Rated V _R	20	mA
Maximum reverse leakage current		T _J = 125 °C		180	ma
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		10 300	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +175	°C	
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.26	°C/W	
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1		
Annual in the surface to				75	g	
Approximate weight			2.7	oz.		
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm	
	busbar		spread of the compound.	3	11111	
Case style			JEDEC®	TO-240AA co	ompatible	

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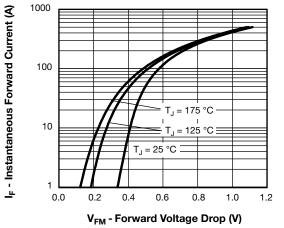
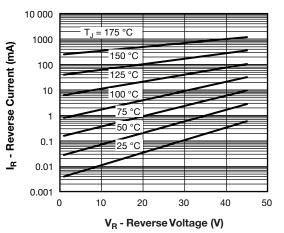
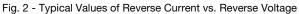


Fig. 1 - Maximum Forward Voltage Drop Characteristics





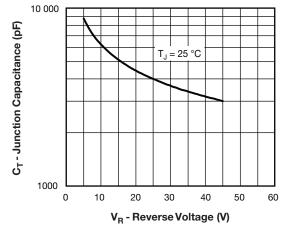


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

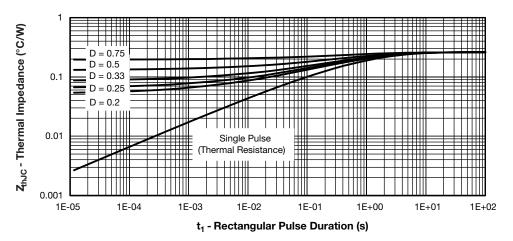


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

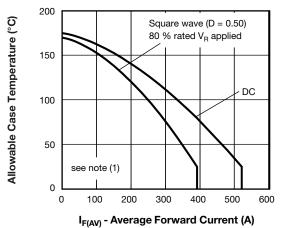
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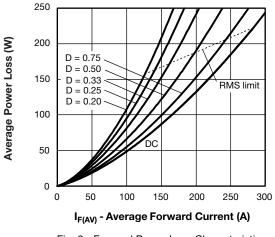
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Average Forward Current





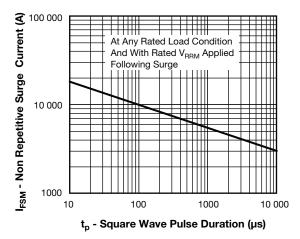


Fig. 7 - Maximum Non-Repetitive Surge Current

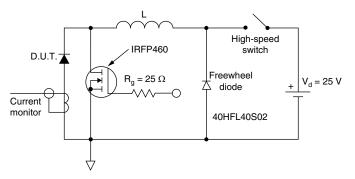


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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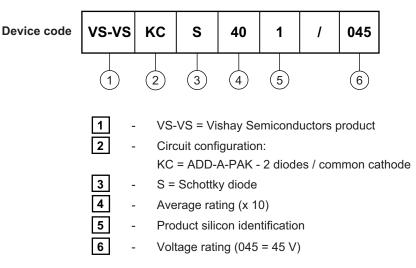
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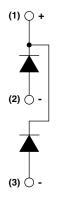
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ORDERING INFORMATION TABLE



CIRCUIT CONFIGURATION



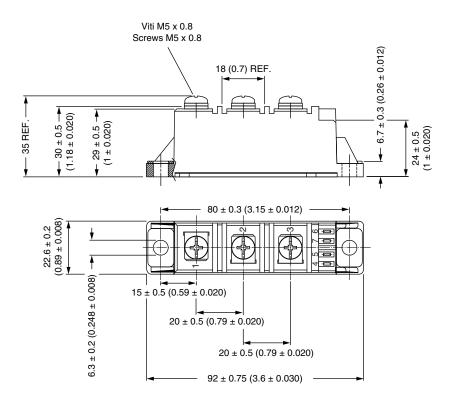
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95369			

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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